Spatially resolved excitation of Rydberg atoms and surface effects on an atom chip

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We demonstrate spatially resolved, coherent excitation of Rydberg atoms on an atom chip. Electromagnetically induced transparency (EIT) is used to investigate the properties of the Rydberg atoms near the gold-coated chip surface. We measure distance-dependent shifts (~10 MHz) of the Rydberg energy levels caused by a spatially inhomogeneous electric field. The measured field strength and distance dependence is in agreement with a simple model for the electric field produced by a localized patch of Rb adsorbates deposited on the chip surface during experiments. The EIT resonances remain narrow (<4 MHz) and the observed widths are independent of atom-surface distance down to ~20 μm, indicating relatively long lifetime of the Rydberg states. Our results open the way to studies of dipolar physics, collective excitations, quantum metrology, and quantum information processing involving interacting Rydberg excited atoms on atom chips.

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I. INTRODUCTION

Ultracold atoms on atom chips are key to new atom-based technologies such as interferometers and precision sensors and provide access to fundamental aspects of many-body physics, atom-surface interactions, quantum metrology, and quantum information science [1, 2]. So far, experiments have dealt with atoms prepared in the electronic ground state, due to their intrinsic stability. Despite their weak interactions, ground-state atoms on atom chips have been used to sensitively probe the intrinsic thermal noise near surfaces [3–5], map magnetic and electric field distributions [6–11], and investigate the Casimir-Polder potential in the micrometer range [12–14]. Comparatively, atoms excited to high-lying Rydberg states have extremely large transition dipole moments (scaling with n^2) resulting in long-range interactions and have large electric polarizabilities (∝ n^2) which can greatly enhance both atom-atom and atom-surface interactions.

Recent experiments with Rydberg atoms have largely been motivated by the excitation blockade mechanism [15, 16]. This made possible the experimental demonstration of a two-qubit quantum gate and entanglement between neutral atoms in separate microtraps [17, 18]. Interactions can be further enhanced and controlled in the presence of modest electric fields via Förster resonances [19] over distances of tens of micrometers [20–22]. We aim to employ Rydberg blockade to optically control interactions between atomic ensembles prepared in separate magnetic microtraps on a magnetic lattice atom chip [23, 24]. Here, an unknown factor is the influence of the nearby metallic surface on the lifetime and coherence properties of the excited Rydberg atoms.

In this paper, we report the coherent excitation of Rydberg atoms on an atom chip [25]. To probe the atom-surface potential and lifetime of the Rydberg states we employ excited-state electromagnetically induced transparency (EIT) [26, 27]. The position and width of the narrow transmission resonance reflect the energy and lifetime of the Rydberg state and provide a sensitive probe of the atom-surface interaction. This is related to a recent experiment investigating Rydberg excitation in a room-temperature glass vapor cell at very small distances to the walls [28]. Here we investigate the effects of a metallic atom-chip surface with ultracold Rydberg atoms.

II. ELECTROMAGNETICALLY INDUCED TRANSPARENCY

Electromagnetically induced transparency is a coherent interference effect where the absorption on a resonant transition between two states is strongly modified by a coupling to a third state, creating a narrow transparency window. A common EIT configuration [29, 30] is the ladder-type system investigated here. We probe the absorption on the 5s-5p transition of ^87Rb, with the 5p state strongly coupled to a resonant laser to a highly excited nd or ns Rydberg state, as is depicted in Fig. 1(a).

In this experiment, the coupling laser is frequency stabilized directly to the 5p transition such that the transparency window is near the center of the resonance. In the limit of low probe intensity the susceptibility is given:

\[ \chi(\Delta_p) \propto \frac{i \Gamma_p}{\Gamma_p + 2i \Delta_p + \frac{\Omega^2}{\Gamma_r + 2i(\Delta_p + \Delta_c)}}, \]

where the probe absorption is proportional to the imaginary part Im(χ) [30]. In this equation, Γ_p and Γ_r denote the decay rates of the probe and coupling resonances, respectively, Δ_p and Δ_c the detunings, and Ω_c the Rabi frequency of the upper transition [Fig. 1(a)].

If the Rydberg energy level shifts due to atom-atom or atom-surface interaction, this leads to a detuning of the coupling laser from resonance which is visible as a shift of the transparency window in the absorption profile by a frequency Δ_c. Furthermore, if the lifetime of the Rydberg state decreases (e.g., through induced decay to neighboring states, this leads to a broadening of the transparency window, visible as an increase of Γ_r. Excited-state EIT is thus a sensitive probe to measure interactions in a Rydberg state.

III. EXPERIMENTAL SETUP

We trap approximately 7 × 10^5 ^87Rb |F = 2, m_f = 2⟩ atoms in a magnetic Ioffe-Pritchard–type trap. The magnetic
are 3 and expand freely for 2 ms in a uniform magnetic field of in detail in [24].

The atoms are cooled to temperatures of a but this does not significantly influence the experiments discussed here. The atoms are cooled to temperatures of a few \( \mu K \) by forced evaporative cooling. This setup is described in detail in [24].

Prior to detection, the atoms are released from the trap and expand freely for 2 ms in a uniform magnetic field of 1G parallel to the probe beam. Typical peak atomic densities are \( 3 \times 10^9 \, \text{cm}^{-3} \). After expansion the vertical extension of the cloud is 100 \( \mu \text{m} \) and the cloud center is 130(10) \( \mu \text{m} \) from the surface [see Fig. 1(c)]. The expanded cloud minimizes possible effects of atom-atom interactions and allows simultaneous probing of many atom-surface distances.

We measure EIT spectra by simultaneously pulsing on a circularly polarized probe and a counterpropagating linearly polarized (perpendicular to the chip surface) coupling laser beam for 0.15 ms and recording an absorption image of the probe with a CCD camera for a variable detuning \( \Delta p \). The resolution of our imaging system is \( \sim 7 \, \mu \text{m} \). The probe beam is approximately uniform and much larger than the atom cloud, whereas the counterpropagating coupling laser beam is passed through an aperture and is imaged onto the atoms. The width of the coupling beam is \( \sim 60 \, \mu \text{m} \) and it extends \( \sim 150 \, \mu \text{m} \) from the chip surface, significantly smaller than the size of the atom cloud (i.e., only part of the cloud is exposed to the coupling beam and thus rendered transparent). This situation is depicted in Fig. 1(b), and the spatial extent of the coupling beam is clearly visible as a light region (low optical density) centered around \( x = 100 \, \mu \text{m}, z = 50 \, \mu \text{m} \) in Fig. 1(c).

The probe laser is frequency stabilized directly to the \( F = 2 \rightarrow F' = 3 \) transition using Doppler-free polarization spectroscopy in a vapor cell. We estimate the linewidth of the laser around \( \sim 500 \, \text{kHz} \) by beating it against an identical laser. To measure absorption spectra, it is frequency shifted using a pair of double-pass AOMs which allow detunings between ± 20 MHz. The coupling beam is produced by a frequency-doubled cw diode laser (Toptica TA-SHG). It is directly locked to the Rydberg state of interest by vapor cell EIT as described in [31]. This allows direct stable locking to both \( s \)- and \( d \)-Rydberg states in the range \( n = 19...70 \); the fine structure of the \( d \) states is also well resolved in the spectroscopy. We estimate the combined (two-photon) linewidth of the Rydberg excitation lasers to be between 0.5 and 2 MHz, depending on the Rydberg state used.

We extract spectra from a series of absorption images such as the one shown in Fig. 1(c). By analyzing a series of such images taken for different detunings of the probe laser we construct an absorption spectrum as a function of detuning and distance to the surface. The coupling laser remains fixed in both position and frequency. For each detuning we take one image with the coupling laser present, and a reference image without the coupling laser. By analyzing each pixel of these images separately we obtain spatially resolved information about the transparency of the sample. In particular, this allows us to extract information for a large number of distances from the surface of the atom chip at once. The dashed line in Fig. 1(c) denotes the peak EIT signal and is used to extract EIT spectra at different distances to the chip. A small angle between the beam profile and the surface normal helps to align the coupling beam parallel to the surface and minimize fringing.

IV. RYDBERG ATOMS ON AN ATOM CHIP

Figure 2 shows an absorption spectrum measured in the absence of the coupling beam (square points), along with a spectrum measured with the coupling beam present (circles), for a relatively large atom-surface distance of \( z \sim 200 \, \mu \text{m} \). The former simply reflects the natural absorption lineshape of the \( ^{87}\text{Rb} \, 5s \rightarrow 5p \) transition and is used as a reference. The latter

![Figure 2](image2.png)

**FIG. 2.** (Color online) Optical spectra extracted from a series of absorption images for 80 probe detunings, with coupling to the \( 38d_{5/2} \) Rydberg state. Square points indicate the measured optical density spectrum taken in the absence of the coupling laser, with a fit to Eq. (1) with \( \Omega_c = 0 \) (dashed line). Circles correspond to the EIT spectrum with the solid line a fit to the data using Eq. (1). Both spectra are obtained at a distance of \( \sim 200 \, \mu \text{m} \) from the surface of the chip.
The spectrum shows the EIT dip resulting from strong coupling to the $38d_{5/2}$ Rydberg state. The transparency window is close to the center of the $5\ell \rightarrow 5p$ resonance. We can extract relevant parameters, in particular the linewidth and the detuning of the Rydberg state from these measurements by fitting the model of Eq. (1). For the spectrum of Fig. 2 we find $\Delta_5 = 0.54(7)$ MHz and $\Gamma_e = 0.61(8)$ MHz. The narrowest spectrum we have observed had a linewidth of 0.4(3) MHz for the state $23\ell_{1/2}$ at a distance of 115 $\mu$m from the chip, consistent with our estimates for the combined laser linewidth. The nonzero fitted value of $\Delta_5$, is due to a small offset in the locking of the probe and coupling lasers, and constitutes a constant offset which is subtracted in later analysis. The measured EIT spectra demonstrate the coherent excitation of Rydberg atoms on an atom chip, in the distance range relevant to typical atom chip experiments. The width of the resonance is currently determined by the linewidth of the excitation laser system.

V. SURFACE EFFECTS

Figure 3 shows the fitted detuning of the EIT resonances as a function of distance to the surface for various excited states in the range $n = 22–36$. Example spectra with fits for some observed level shifts are shown in Figs. 3(a) and 3(b) for the state $36d_{5/2}$ and in Fig. 3(c) for the state $23\ell_{1/2}$. The dashed vertical line indicates the extrapolated position of the EIT resonance for large distances [subtracted in Fig. 3(d)]; a significant distance-dependent shift of the fitted resonance position is clearly recognizable. A positive shift of the detuning is equivalent to a shift of the Rydberg level toward higher energies.

We investigate $s$ states $|\ell = 0, j = \frac{1}{2}\rangle$ as well as $d$ states where $|\ell = 2, j = \frac{5}{2}\rangle$ and $|\ell = 2, j = \frac{3}{2}\rangle$. The distance range probed in the experiments is between 20 and 200 $\mu$m and in this range we observe shifts between −15 and +20 MHz. The measured $n$ dependence is $\propto n^{6.2\pm0.3}$, however, there are significant differences between measured shifts for the $s$, $d_{3/2}$, and $d_{5/2}$ states.

Notably, the measured shifts for the $d_{3/2}$ states have the opposite sign as compared with the $s_{1/2}$ and $d_{3/2}$ states. This we attribute to the differing dc electric polarization $\alpha$ for the studied states indicating the shifts originate from spatially varying electric fields. We compute $\alpha$ from perturbation theory based on the analytical radial matrix elements in terms of Appell F2 functions, including their dependence on $j$ and $|m_j|$ quantum numbers [32], using precise values for the $^{87}\text{Rb}$ quantum defects [33]. The calculated values are in excellent agreement with tabulated measurements for the scalar and tensor polarizabilities from previous Stark shift measurements of the $s$ and $d$ states of $^{85}\text{Rb}$ [34,35]. In particular, we find that for $nd_{5/2}/|m_j|=1/2$, $\alpha$ is negative for the measured states, whereas the $s$ and $d_{5/2}/|m_j|=3/2$ states have a positive sign. From the measured shifts we conclude that the dominant states probed in these experiments are $s_{1/2,1/2}, d_{3/2,3/2}$, and $d_{5/2,1/2}$. The other $|m_j|$ states are expected to shift at a different range of distances than those investigated, and could have an influence for larger distances. For example, for the state $22d_{5/2}$, the electric polarization $\alpha$ for $|m_j|=\frac{3}{2}$ and $|m_j|=\frac{5}{2}$ is about 3 and 10 times larger, respectively, than for the probed state $|m_j|=\frac{1}{2}$.

The spectra also provide information on the Rydberg lifetime through the parameter $\Gamma_e$. As can be seen in Fig. 3(e), the fitted values of $\Gamma_e$ do not measurably depend on the distance to the chip surface. The observed linewidths are of the order of the linewidth measured at large distances to the chip, which is limited by the linewidth of our laser system [see Fig. 2(a)]. For some of the data we see evidence for other $|m_j|$ states as double EIT resonances, which may result in artificially large fitted values for $\Gamma_e$. Some broadening of the EIT resonances ($\Gamma_e \sim 0.2\Delta_5$) is also expected due to integration over the inhomogeneous electric field over the atomic distribution along the probe axis during imaging. The largest fitted value for $\Gamma_e$ we observed in any measurement was below 4 MHz, giving a lower bound for the Rydberg lifetime of 0.04 $\mu$s.

Shown in Fig. 4 are values for the local electric field strength $|E| = \sqrt{2|\Delta_e|/\Delta_5}$ inferred from the measured Rydberg energy-level shifts. The measurements are identical to those presented in Fig. 3; they span from $n = 22–36$ and include $s$, $d_{3/2}$, and $d_{5/2}$ angular momentum states covering a wide range of electric polarizabilities. In this form, all data fall on a single curve, confirming that the measured line shifts are caused by an inhomogeneous electric field originating from the chip surface. The height dependence of the field strength roughly follows a weak power-law decay $\propto z^{-0.7}$, thus excluding effects due to Van der Waals interactions ($\propto z^{-3}$) [11] or randomly distributed patch potentials expected to scale with $z^{-2}$. We also expect a contribution from the Van der Waals interaction for e.g., $26s$ of only $\sim0.1$ kHz at 80 $\mu$m. The presented data
The peak field strength at the center of the atom cloud (over the d with the field originates from a Gaussian patch of surface dipoles (see inset)

the measured Rydberg energy-level shifts and averaged over the probe

Ez by the surface. At the center of the patch the field is given
gives the total electric field as a function of distance from

Gaussian distribution of atoms released from the magnetic

surface and assume a patch of adsorbates which reflects the

as an electric dipole oriented perpendicular to the chip

study of dipolar physics, strongly interacting systems, and

quantum information science in tailored trapping potentials.

Atom chips allow the preparation of small atomic clouds [24]

highly excited Rydberg atoms on atom chips, as demonstrated

here for the first time, open new avenues for the study of dipolar physics, strongly interacting systems, and quantum information science in tailored trapping potentials. Atom chips allow the preparation of small atomic clouds [24] ideal for investigating dipole-dipole interactions and collective excitations in dense (10^{15} \text{cm}^{-3}) mesoscopic ensembles [38,39]. Furthermore, Rydberg atoms on atom chips are very attractive for studying long-range Van der Waals interactions with surfaces [11] and interfacing ultracold atoms with on-chip structures [40,41].

VI. CONCLUSION

The present experiments focus on spatially resolved excitation of Rydberg atoms on an atom chip. We create Rydberg atoms in a cloud of rubidium atoms on an atom chip, and investigate electromagnetically induced transparency near the chip surface. Absorption imaging in conjunction with the recording of EIT signals is used to obtain spatially resolved EIT spectra. We measure significant shifts of the Rydberg levels as we approach the surface which we attribute to electric fields produced by adatoms adsorbed on the chip surface. A theoretical model of the field produced by a Gaussian distribution of surface dipoles is in good agreement with our data. We do not observe significant broadening of the Rydberg levels. The measured shifts are not expected to inhibit the coherent creation and investigation of Rydberg atoms on atom chips.

We clearly see that the shifts are directly proportional to the polarizabilities of the states in question. This opens new possibilities to use Rydberg excited atoms as a sensitive, spatially resolved probe of electric fields [36,37]. A simple estimate of our present sensitivity to electric fields is \( \sim 0.1 \text{ V/cm} \) with a resolution 7 \( \mu \text{m} \). The field sensitivity could be straightforwardly improved using narrow linewidth lasers and higher-lying Rydberg states.

The surface effects due to adatoms observed here could be prevented in future experiments by incorporating a magnetic field gradient to push the atoms away from the surface at the end of each experimental cycle. Furthermore, use of other coating materials on the chip surface could decrease the dipole moment of adatoms, or increase the desorption rate of these atoms.

Highly excited Rydberg atoms on atom chips, as demonstrated here for the first time, open new avenues for the study of dipolar physics, strongly interacting systems, and quantum information science in tailored trapping potentials. Atom chips allow the preparation of small atomic clouds [24] ideal for investigating dipole-dipole interactions and collective excitations in dense (10^{15} \text{cm}^{-3}) mesoscopic ensembles [38,39]. Furthermore, Rydberg atoms on atom chips are very attractive for studying long-range Van der Waals interactions with surfaces [11] and interfacing ultracold atoms with on-chip structures [40,41].

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FIG. 4. (Color online) Local electric field strength inferred from the measured Rydberg energy-level shifts and averaged over the probe direction. The solid line shows the results of a fit to the data assuming the field originates from a Gaussian patch of surface dipoles (see inset) with \( d_o = 7 \times 10^5 \text{Debye}/\mu \text{m}^2 \), and radius \( w = 100 \mu \text{m} \), averaged over the \( e^{-1/2} \) cloud radius of \( \sigma_z = 130 \mu \text{m} \). The dotted line indicates the peak field strength at the center of the atom cloud \( (y = 0) \).
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